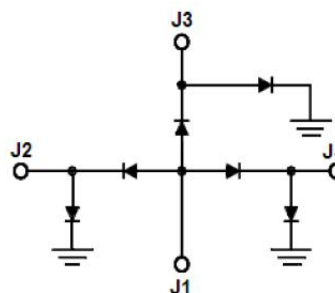


## GaAs PIN Reflective Single-pole Triple-throw Switch Chip, 0.05 - 50GHz

### Performance characteristics

- Frequency range: 0.05-50 GHz
- Insertion loss : 1.0 dB typ.
- Isolation: 44 dB typ.
- P-1dB: See the table below
- 50Ohm input / output
- 100% on-wafer testing
- Chip size: 1.37 x 1.37 x 0.1mm
- Silicon nitride passivation, scratch protection

### Functional Block Diagram



### Product Introduction

GSW3D is a GaAs PIN reflective single-pole triple-throw switch chip with 50Ω matching at the input/output ends, a frequency range of 0.05~50GHz , and -5V/+5V control.

#### Use restriction parameter <sup>1</sup>

Maximum input voltage	2.5V
Maximum input power	+35dBm CW
Operating temperature	-55 ~ +85°C
storage temperature	-65 ~ +150°C

【1】 Exceeding any of these maximum limits may cause permanent damage.

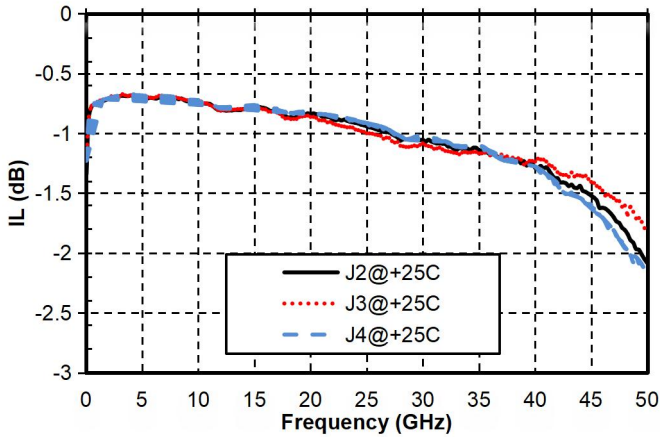
#### Electrical performance parameters ( TA = +25°C)

index	Minimum	Typical Value	Maximum	unit
Frequency Range	0.05-50			GHz
Insertion loss	-	1.0	-	dB
Isolation	-	44	-	dB
Input return loss	-	17	-	dB
Output return loss	-	20	-	dB
P-1dB	-	25.5@1GHz	-	dBm
	-	30.5@2GHz	-	
	-	31.5@4GHz	-	
	-	32.5@8GHz	-	
	-	33.5@12GHz	-	
	-	33.0@16GHz	-	
	-	30.5@20GHz	-	
	-	29.0@34GHz	-	
Switching speed	-	20	-	ns

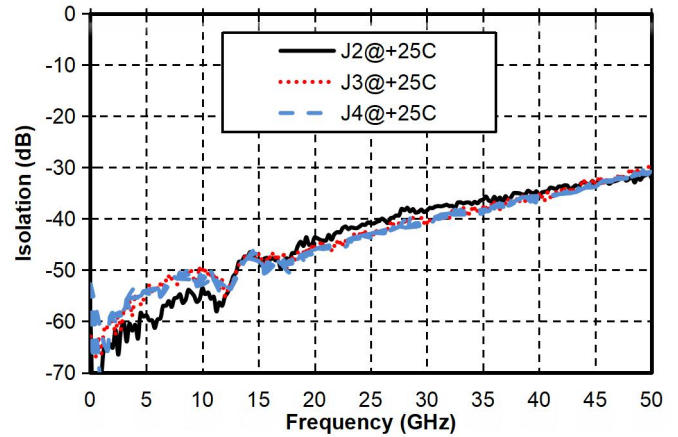
## GaAs PIN Reflective Single-pole Triple-throw Switch Chip, 0.05-50GHz

Main index test curve

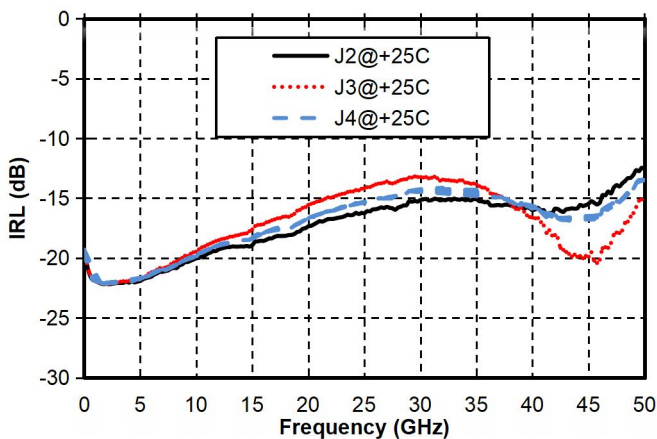
Insertion Loss vs. Operating Frequency



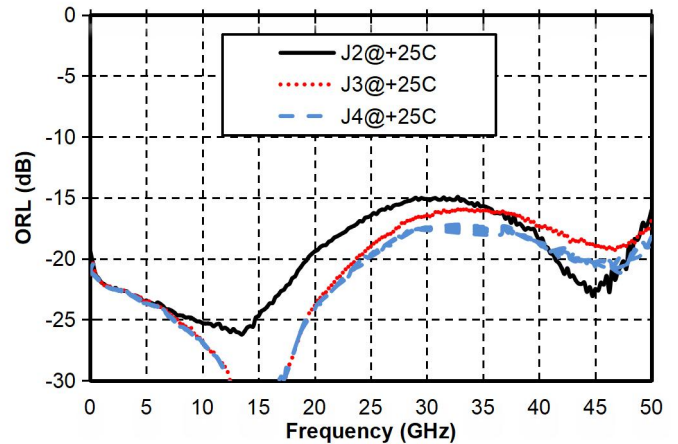
Isolation vs. Operating Frequency



Input Return Loss vs. Frequency



Output Return Loss vs. Frequency



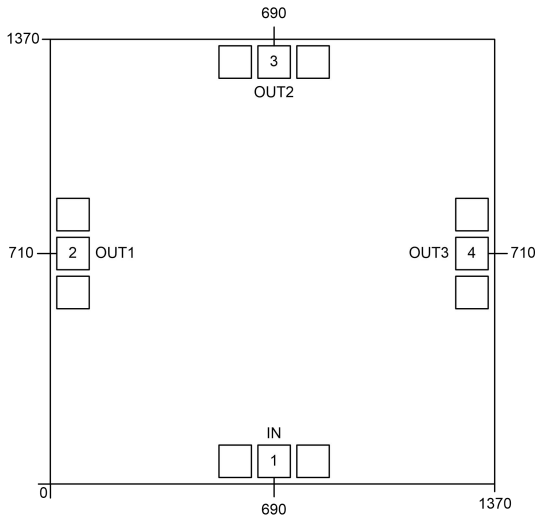
### Typical Driver Connections

CONTROL LEVEL (DC CURRENT)			RF OUTPUT STATE		
OUT1(J2)	OUT2(J3)	OUT3(J4)	OUT1(J2)-IN(J1)	OUT2(J3)-IN(J1)	OUT3(J4)-IN(J1)
-10mA	+20 mA	+20mA	Low Loss	Isolation	Isolation
+20mA	-10mA	+20mA	Isolation	Low Loss	Isolation
+20mA	+20mA	-10mA	Isolation	Isolation	Low Loss

Note:  $V \approx +3.8\text{ V}$ ,  $I \approx +20\text{ mA}$ ;  $V \approx -4.4\text{ V}$ ,  $I \approx -10\text{ mA}$  (including J1 end RIN = 50 ohm resistor voltage divider)

## GaAs PIN Reflective Single-pole Triple-throw Switch Chip, 0.05 - 50GHz

### Appearance structure

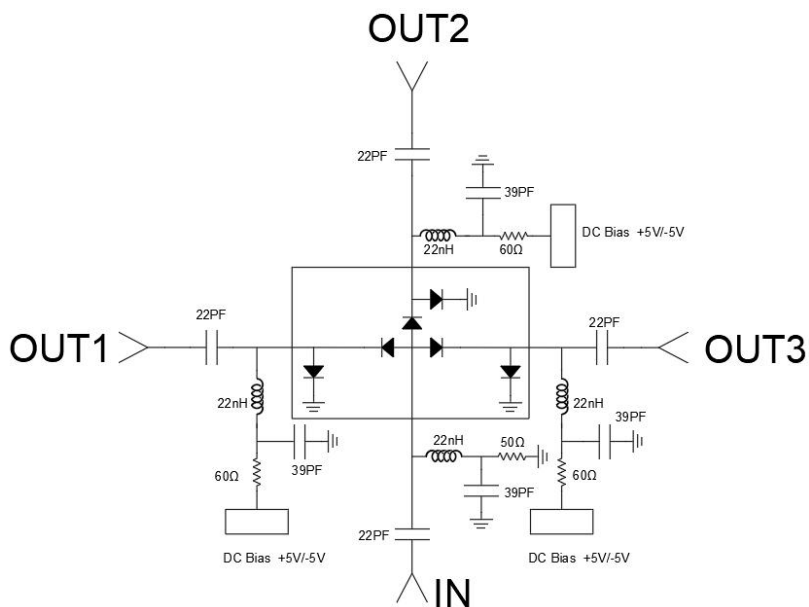


All units in the figure are micrometers

### Bonding point definition

Bonding point number	Function Symbol	Functional Description
1	IN	A DC blocking capacitor is required at the RF input signal end
2, 3, 4	OUT1, 2, 3	The RF output signal terminal needs to be equipped with a DC blocking capacitor
Chip bottom	GND	The bottom of the chip needs to be well grounded to RF and DC

### Recommended circuit diagram



+5V series  $R \approx 60$  ohm resistor,  $V \approx +3.8V$ ,  $I \approx 20mA$ ; -5V series  $R \approx 60$  ohm resistor,  $V \approx -4.4V$ ,  $I \approx -10mA$ . Users can change the resistance value according to their own situation. If there is any problem, please contact the manufacturer.